

# Radon induced surface contaminations in low background experiments

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# OUTLINE

- \* Rare event physics
- \* DBD bolometric experiments
- \* Background sources in bolometric experiments
- \*  $^{222}\text{Rn}$  induced surface contaminations
  - \* Mechanisms
  - \*  $^{222}\text{Rn}$  “Sticking Factor” ( $\Sigma_{\text{Rn}}$ )
- \* Conclusions

# Low background experiments

rare events

DBD2 $\nu$  & DBD0 $\nu$

DM interactions with RM  
rare  $\alpha/\beta$  decays

elusive rates

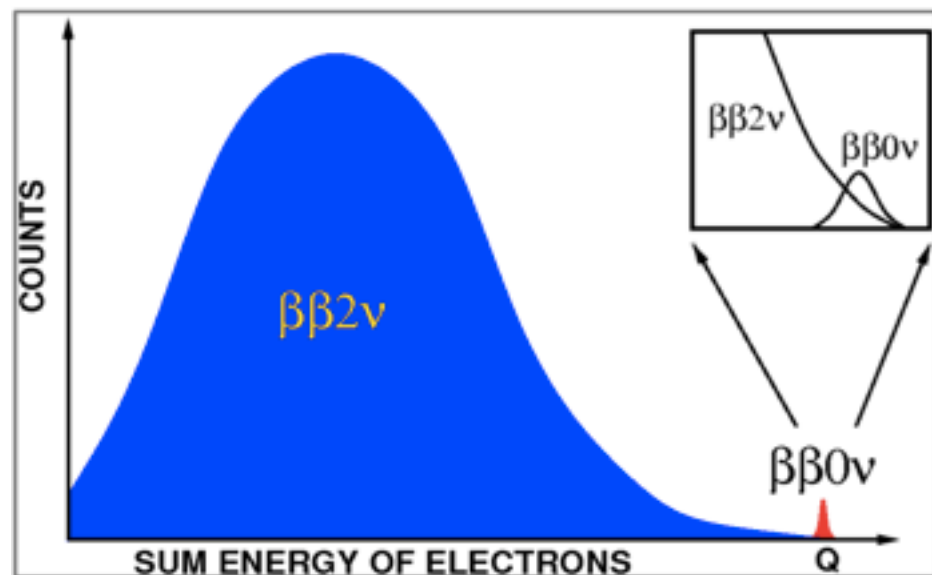
$< 10^{-2}-10^{-4}$  c/keV/kg/y

$< 10^{-3}-10^{-4}$  c/kg/d

$< 10^{-2}-10^{-xx}$  c/kg/d



**DBD signal**

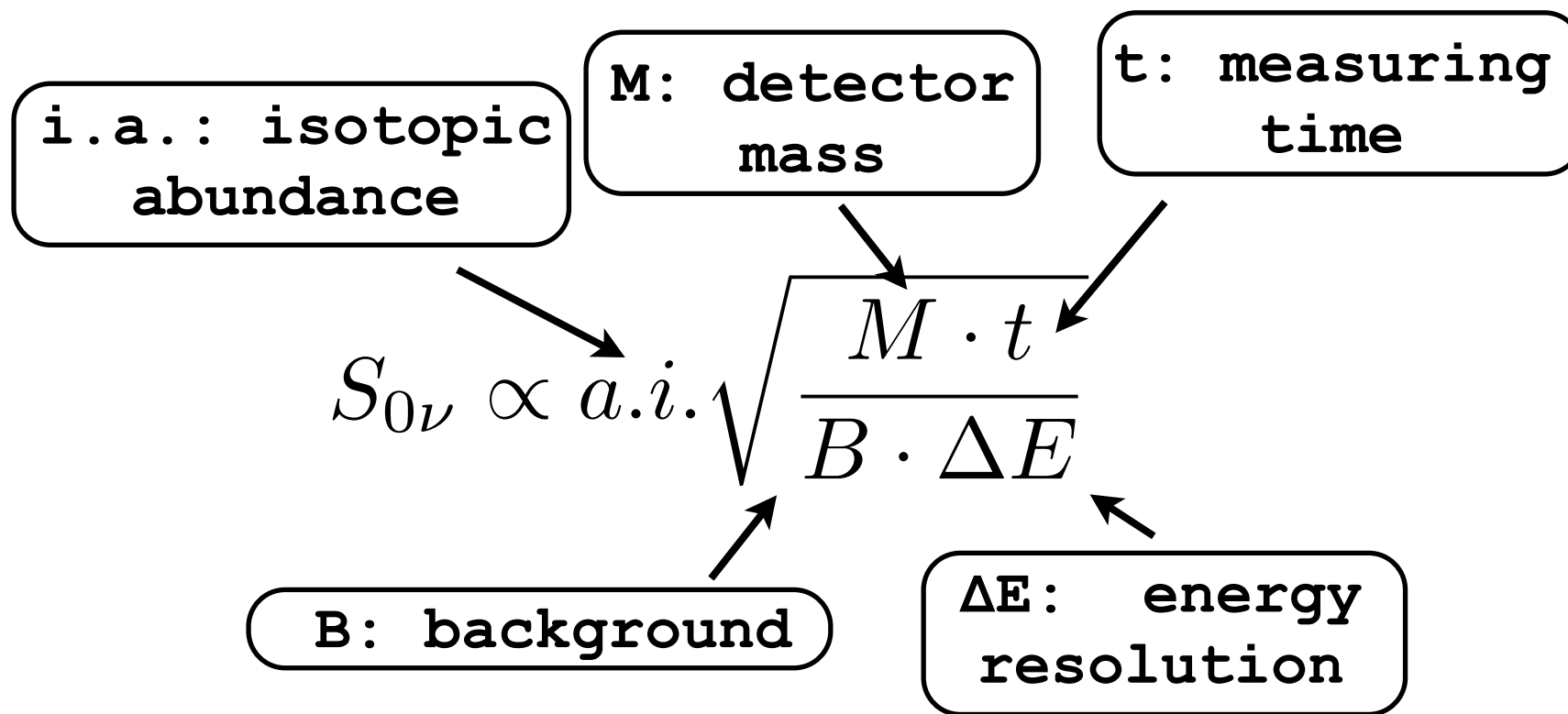


Low radioactive techniques are used:

- \* material selection
- \* underground installation
- \* (re)contamination control
- \* highly sensitive detectors

# Sensitivity for DBD0ν

**$S_{0\nu}$** : half-life corresponding to the minimum number of detectable signals above background at a given C.L.



**Q value:** 2995 keV  
**Material:** ZnSe  
**Enriched a.i.:** 95%  
**Source Mass:** 15 kg of Se-82  
**Projected Bkg:**  $\sim 10^{-3}$  c/keV/kg/y  
**Resolution:**  $\sim 10$  keV @ROI  
**Sensitivity  $T_{1/2}$ :**  $\sim 10^{26}$  y in 5 y



**Q value:** 2528 keV  
**Material:** TeO<sub>2</sub>  
**Natural a.i.:** 34%  
**Source Mass:** 206 kg Te-130  
**Projected Bkg:**  $\sim 0.01$  c/keV/kg/y  
**Resolution:**  $\sim 5$  keV @ROI  
**Sensitivity  $T_{1/2}$ :**  $\sim 10^{26}$  y in 5 y



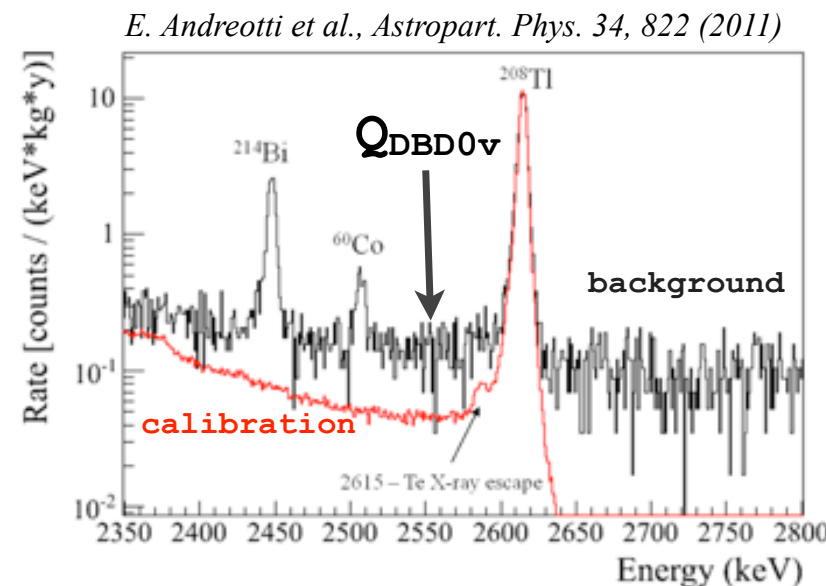
# Surface background issue

- Cuoricino: • first large array (62 bolometers = ~41 kg) for DBD  
 @LNGS • high statistics (exposure:  $19.75 \text{ kg}(\text{Te}^{130}) \times y$ )  
 • energy resolution @ DBD0v:  $6.3 \pm 2.5 \text{ keV}$

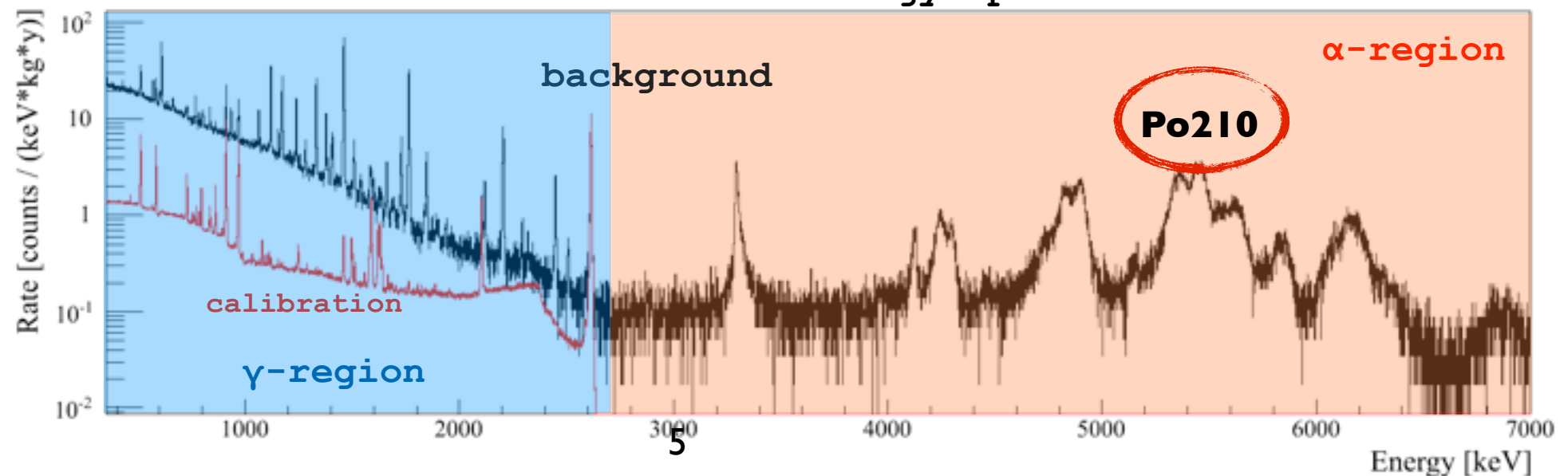
background @ DBD0v (2.5 MeV):  
**0.17 c/keV/kg/y**

External  
 high energy  $\gamma$  (232Th) **35%**

Degraded  $\alpha$  struggling  
 from  $\text{TeO}_2$  and Cu  
 surface  
 contaminations  
 (232Th & 238U) **65%**



CUORICINO final energy spectrum

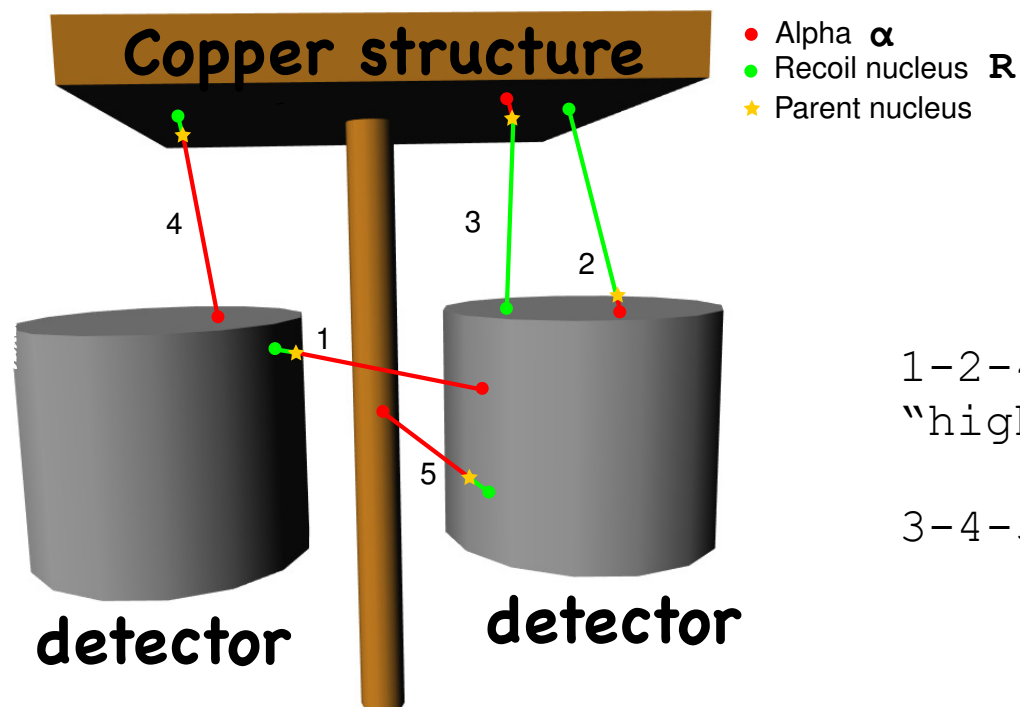


# $\alpha$ surface contaminations

$\alpha$  decays ( $^{210}\text{Po}$ :  $\alpha=5.3$  MeV,  $R=100$  keV) may occur on surfaces of Cu structure or on the detectors

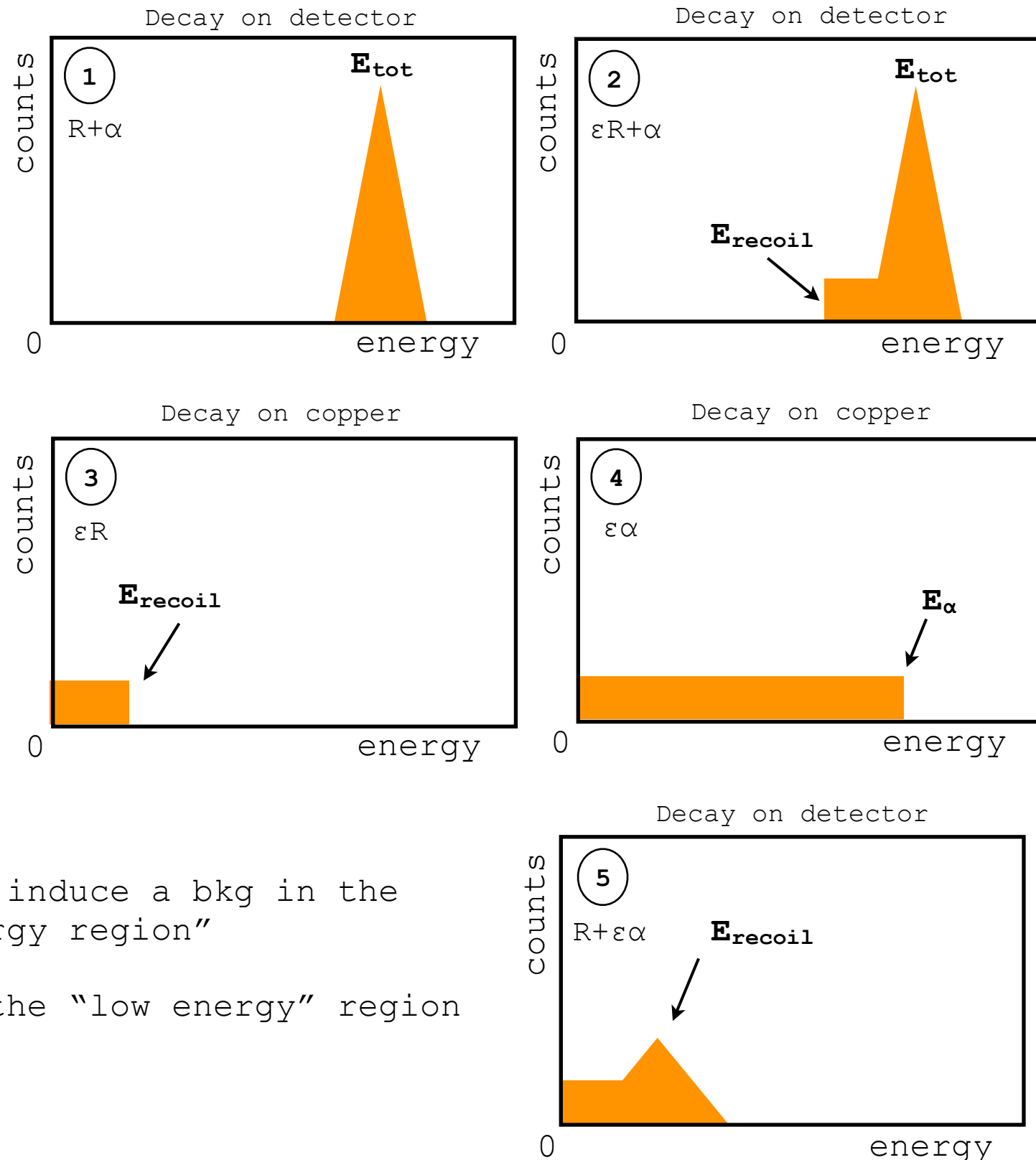
**N.B. bolometers are fully-active detectors**

$$E_{\text{tot}} = E_{\alpha} + E_{\text{recoil}}$$



1-2-4 may induce a bkg in the "high energy region"

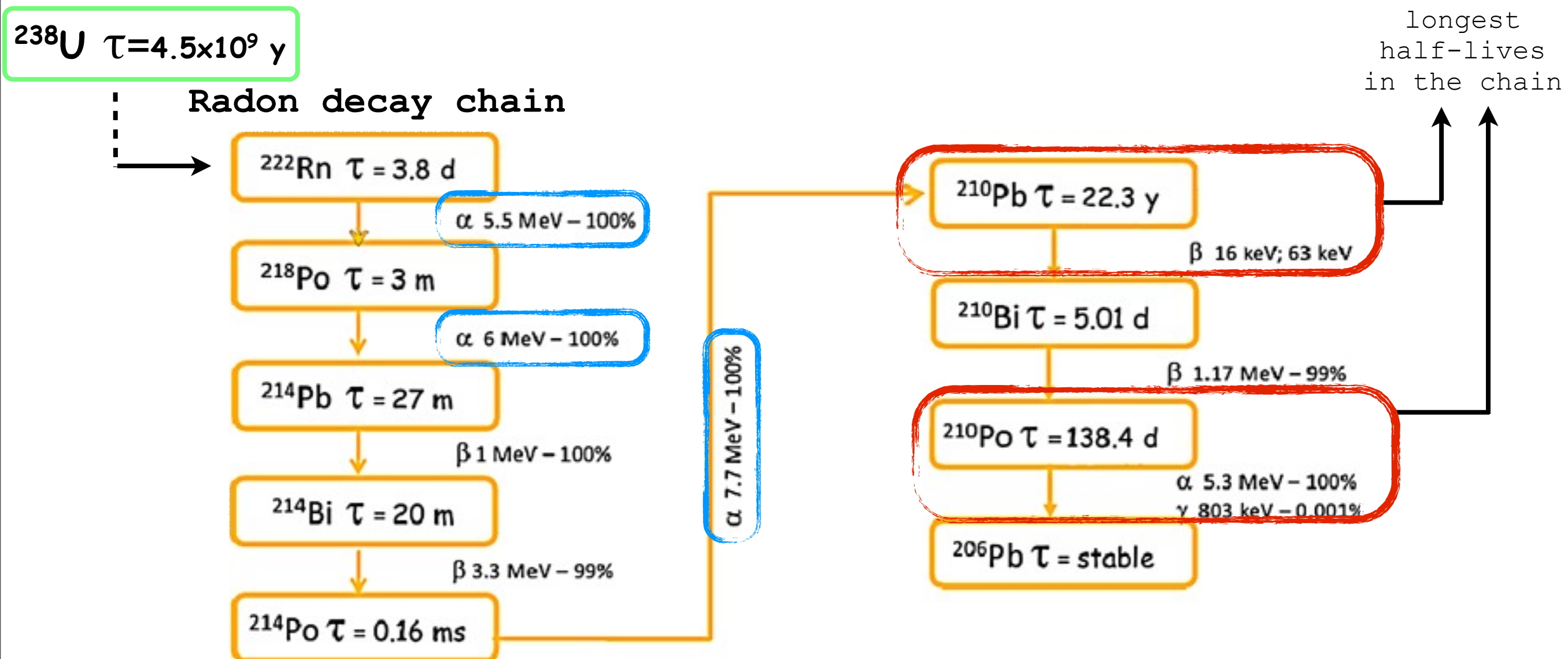
3-4-5 in the "low energy" region





# Radon induced contaminations

$^{210}\text{Po}$  is the most intense source of surface contaminations in DBD bolometric experiments (and not only).



# Why $^{222}\text{Rn}$ ?

Radon is the most intense air-borne contaminant

$^{210}\text{Pb}$  and  $^{210}\text{Po}$  are  $^{222}\text{Rn}$  daughters and background sources

Is  $^{222}\text{Rn}$  the primary source of surface background ?

- \* Storage of material in non-ultra-pure containers
- \* Handling in non-controlled environment
- \* Not appropriate surface cleaning
- \* . . . .

- $^{222}\text{Rn}$  can induce a re/contamination of  $^{210}\text{Pb}$  and  $^{210}\text{Po}$  ?
  - Exposing an radio-pure material to  $^{222}\text{Rn}$  will contaminate the sample?



# $^{222}\text{Rn}$ experiment

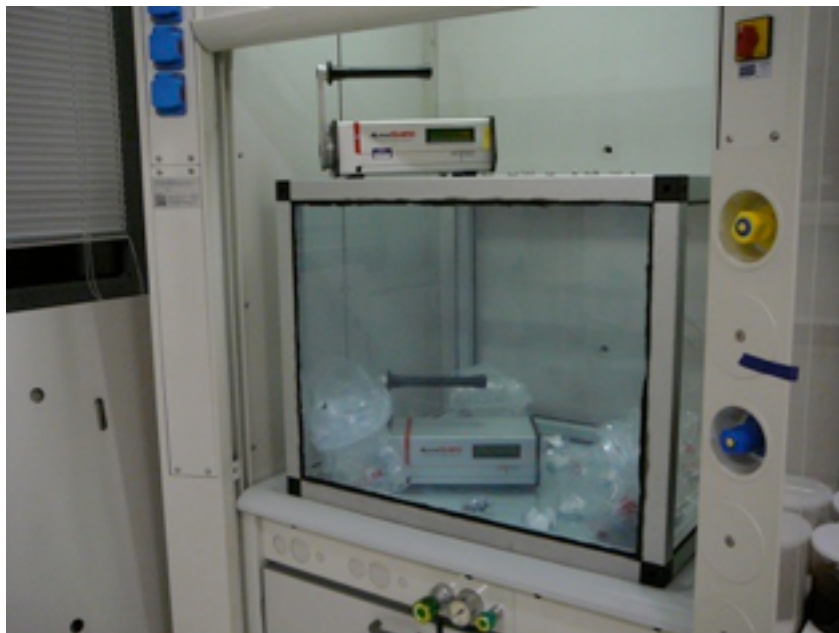
We expressly expose different radio-pure materials to an atmosphere rich in  $^{222}\text{Rn}$ .

We analyze the surface contaminations of the samples due to the exposure.

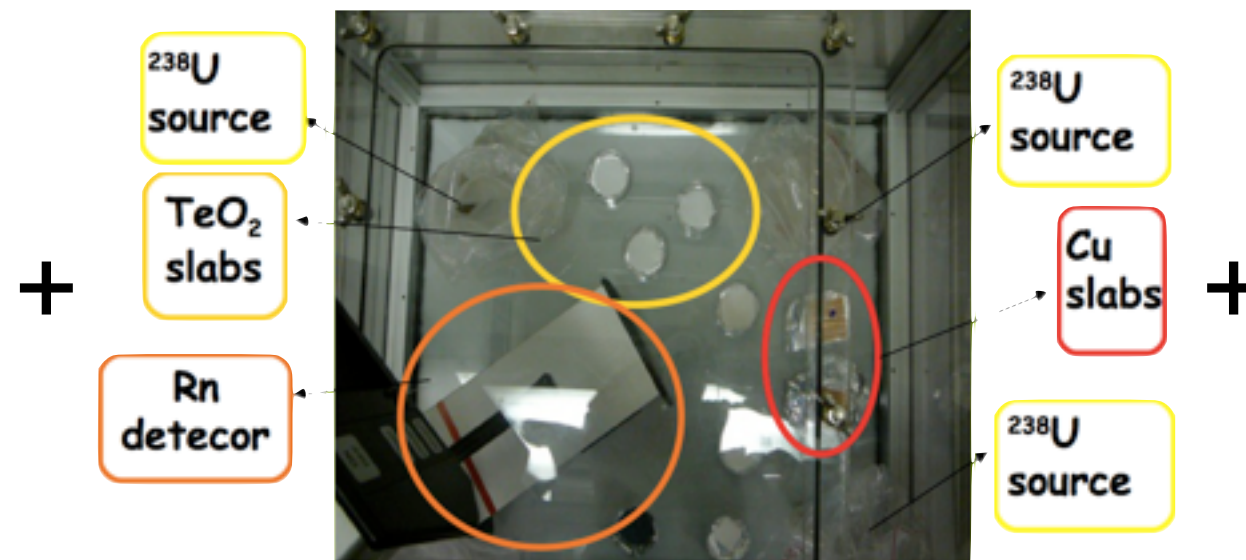
\* We evaluate the probability that a nucleus of  $^{222}\text{Rn}$  (or daughters) can stick on the surface of the sample ( $^{222}\text{Rn}$  Sticking Factor).

\* We analyze the mechanisms/dynamics that lead to sample recontaminations.

Box with hermetic enclosures



Samples and  $^{238}\text{U}$  sources

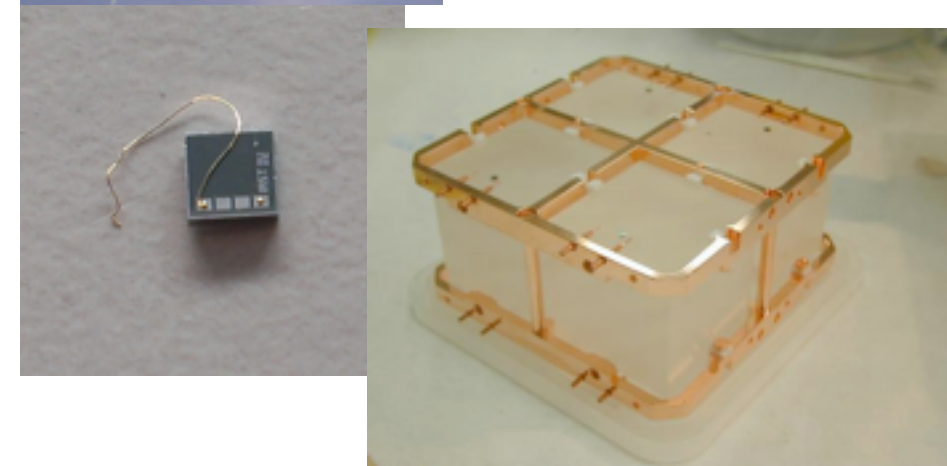
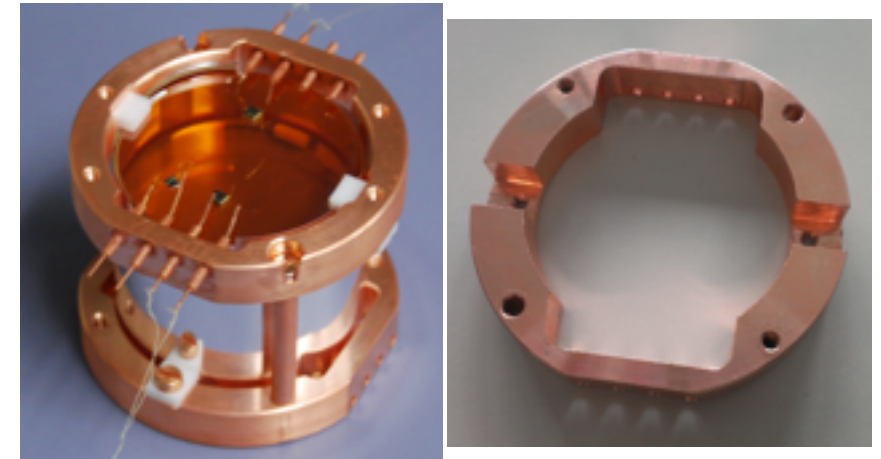
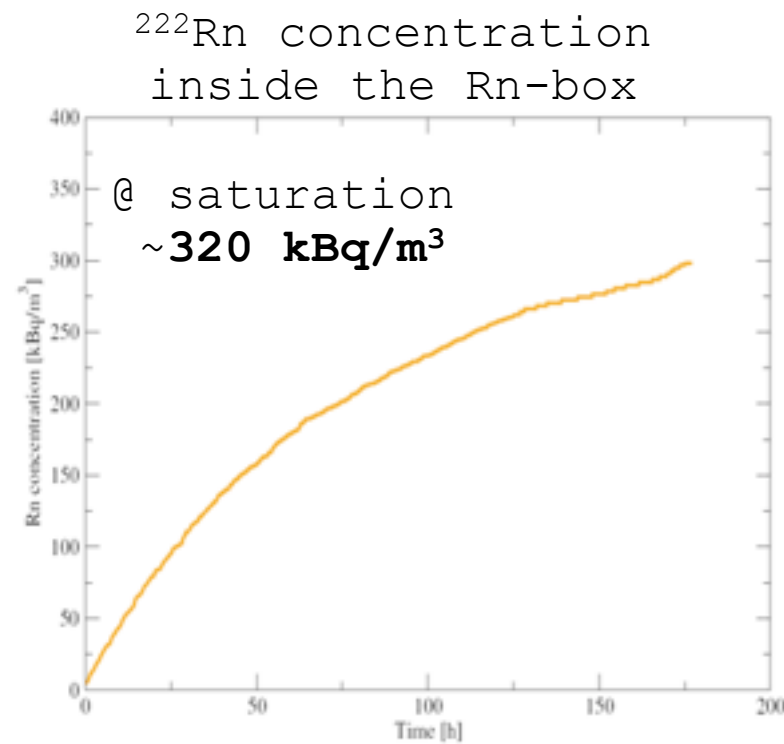


Surface barrier detector

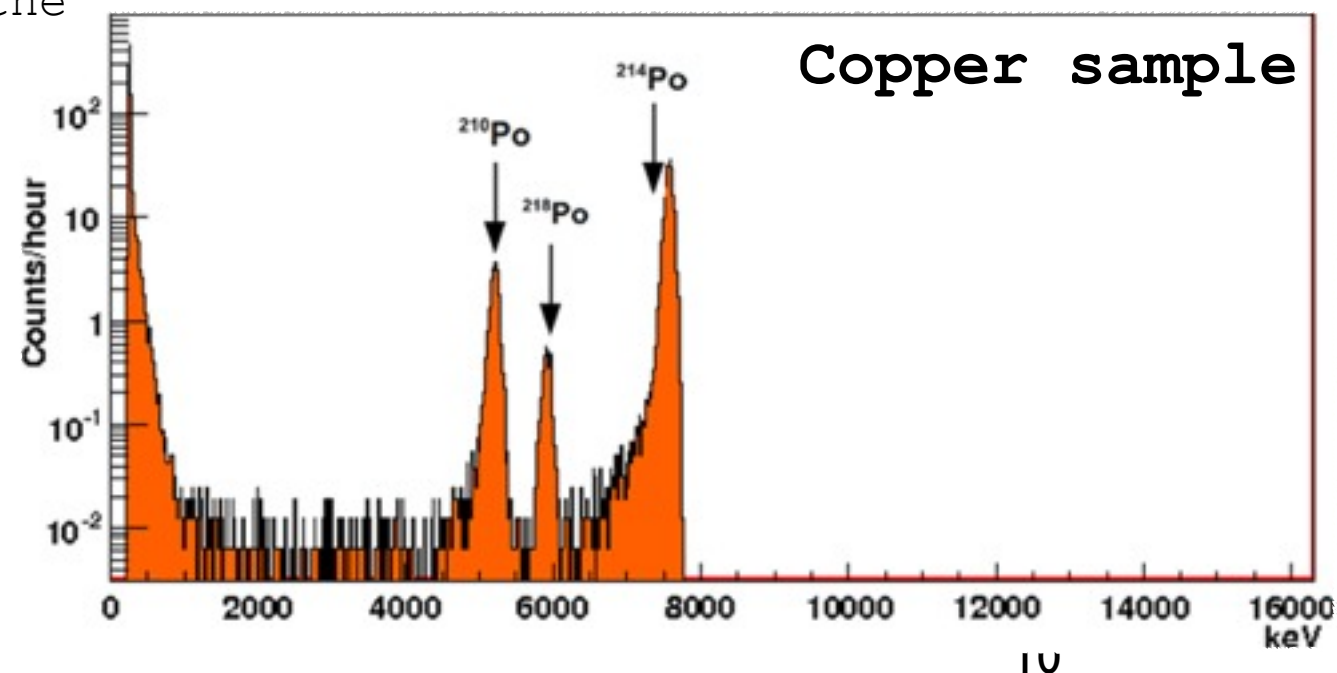


# Samples exposure

MATERIAL	Exposure [days]
Copper	1076
PTFE	1140
Si	1080
TeO <sub>2</sub>	1183
ZnSe	XXXX

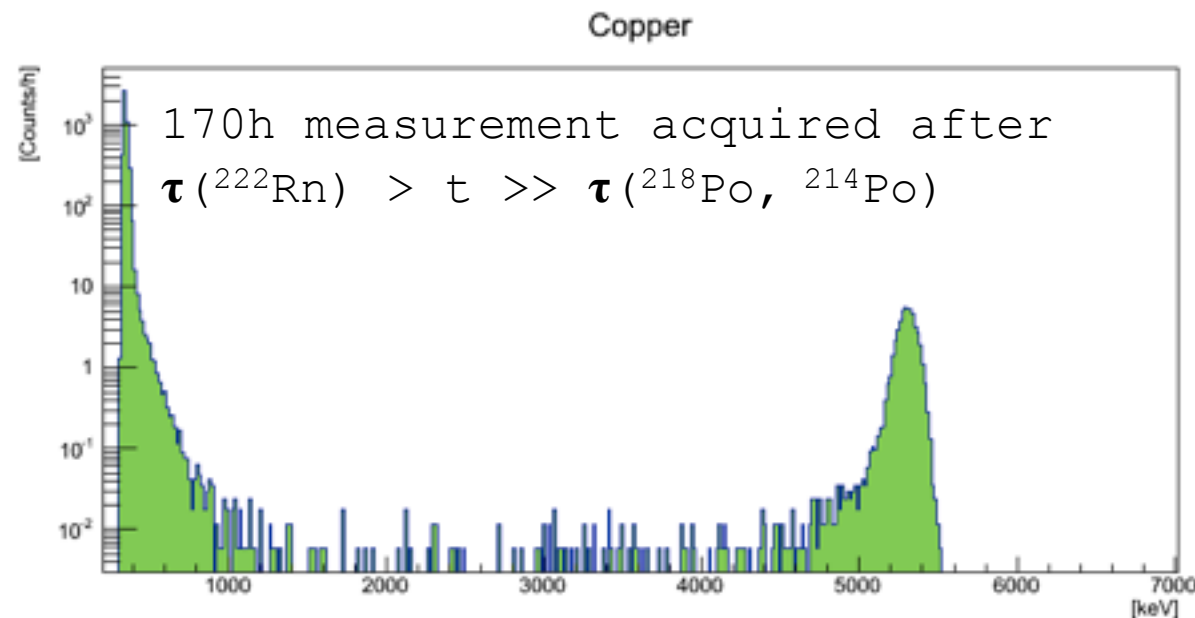


After the exposure we measure the sample



- \* Po isotopes stick to the surfaces
- \* <sup>214</sup>Po and <sup>210</sup>Po peak+tail
- \* Tails extend to low energy

# $^{210}\text{Po}$ contaminant & $\Sigma_{\text{Rn}}$



- \* No evidence of  $^{222}\text{Rn}$  contamination
- \*  $^{210}\text{Po}$  contamination produces a continuum
- \*  $^{210}\text{Po}$  activity is proportional to exposure time (for the same materials)
- \*  $^{210}\text{Po}$  increases with time

**Sticking Factor ( $\Sigma$ )** for a nucleus that interacts with a surface (S) is defined as:

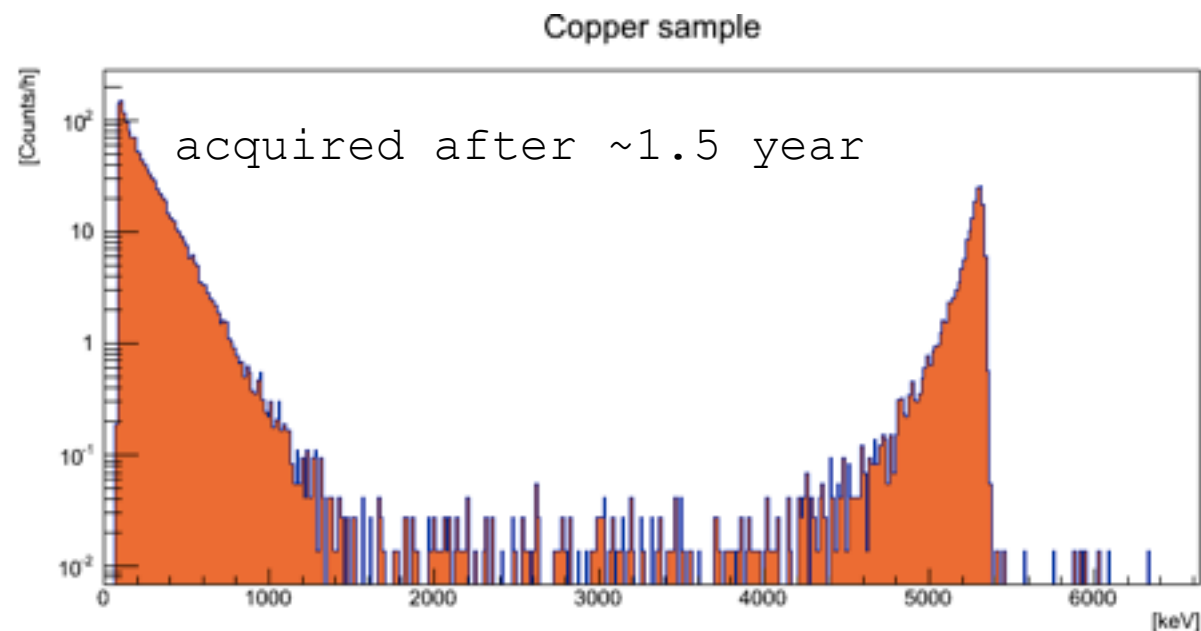
the ratio between the number of nuclei that stick on a surface ( $A_{\text{Pb}}^0 \cdot \tau_{\text{Pb}}$ ) and the total number of nuclei that are close enough to the surface to stick ( $\Gamma \sim \text{Rn concentration}$ ).

$$\Sigma_{\text{Rn}} = \frac{A_{^{210}\text{Pb}}^0 \cdot \tau_{^{210}\text{Pb}}}{\Gamma \cdot S \cdot t_{\text{exp}}}$$

MATERIAL	$\Sigma_{\text{Rn}}$
<b>Copper</b>	$(1.86 \pm 0.10) \cdot 10^{-9}$
<b>PTFE</b>	$(3.06 \pm 0.22) \cdot 10^{-10}$
<b>Si</b>	$(3.97 \pm 0.54) \cdot 10^{-10}$
<b>TeO2</b>	$(3.75 \pm 0.21) \cdot 10^{-10}$
<b>ZnSe</b>	measurement on going

**N.B.** We refer to  $^{210}\text{Pb}$  activity because we assume that after a long period of time ( $t \gg \tau_{1/2\text{Rn}}$ ), all the  $^{222}\text{Rn}$  daughters have decayed and have populated the  $^{210}\text{Pb}$  level.

# $^{210}\text{Po}$ contaminant & $\Sigma_{\text{Rn}}$



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- \*  $^{210}\text{Po}$  contamination produces a continuum
- \*  $^{210}\text{Po}$  activity is proportional to exposure time (for the same material)
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**Sticking Factor ( $\Sigma$ )** for a nucleus that interacts with a surface (S) is defined as:

the ratio between the number of nuclei that stick on a surface ( $A_{\text{Pb}}^0 \cdot \tau_{\text{Pb}}$ ) and the total number of nuclei that are close enough to the surface to stick ( $\Gamma \sim \text{Rn concentration}$ ).

$$\Sigma_{\text{Rn}} = \frac{A_{^{210}\text{Pb}}^0 \cdot \tau_{^{210}\text{Pb}}}{\Gamma \cdot S \cdot t_{\text{exp}}}$$

MATERIAL	$\Sigma_{\text{Rn}}$
Copper	$(1.86 \pm 0.10) \cdot 10^{-9}$
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ZnSe	measurement on going

**N.B.** We refer to  $^{210}\text{Pb}$  activity because we assume that after a long period of time ( $t \gg \tau_{1/2\text{Rn}}$ ), all the  $^{222}\text{Rn}$  daughters have decayed and have populated the  $^{210}\text{Pb}$  level.

$$A_{\text{Po}} = A_{\text{Pb}}^0 \frac{\lambda_{\text{Pb}}}{\lambda_{\text{Po}} - \lambda_{\text{Pb}}} (e^{-\lambda_{\text{Pb}} t} - e^{-\lambda_{\text{Po}} t})$$

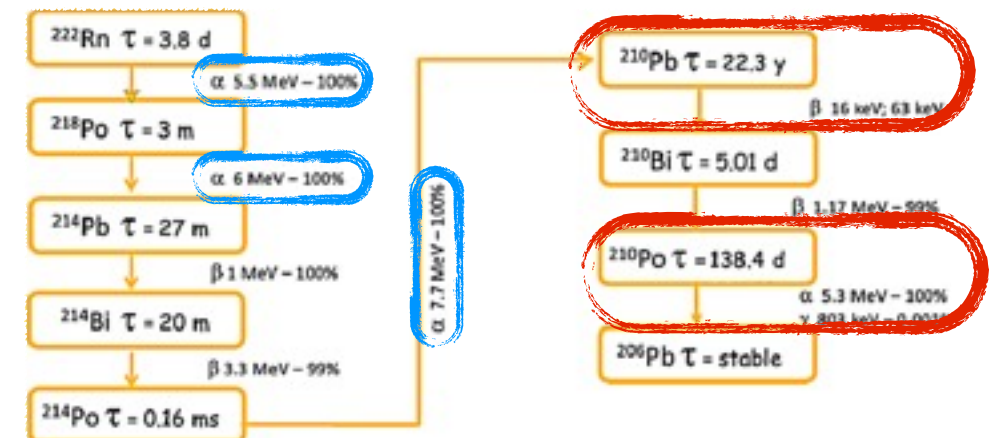


# $^{210}\text{Pb}$ production

$^{210}\text{Po}$  contamination is driven by  $^{210}\text{Pb}$  contamination  
 $\Rightarrow$   $^{210}\text{Po}$  activity does not decrease with time

$^{210}\text{Pb}$  on the surface can be produced by:

- \* direct  $^{210}\text{Pb}$  surface sticking (prompt)
- \*  $^{218}\text{Po}$  &  $^{214}\text{Po}$  isotopes sticking (delayed)



$^{210}\text{Pb}$  evaluated from  $^{210}\text{Po}$  contamination.

"prompt" ( $t \sim \text{h}$ ) and "delayed" ( $t \sim 1.5 \text{ y}$ ).

$^{210}\text{Pb}$  production mechanism

$$A^0(^{210}\text{Pb})_{\text{delay}} / A^0(^{210}\text{Pb})_{\text{prompt}} = \sim 6$$

In Clean Room design Po isotopes contamination must be kept under control



~85% of  $^{210}\text{Pb}$  contamination is generated by  
 Rn fast daughter decays ( $^{218}\text{Po}$  and  $^{214}\text{Po}$ )

# Conclusions

- Surface contaminations are a serious limitation for low background experiments
- Rn exposure of ultra-pure samples induce re/contaminations
- $^{210}\text{Pb}$  (and especially Po isotopes) contaminations must be took under strict controls
- We have evaluated the sticking probability of  $^{222}\text{Rn}$ , long-term exposure are dangerous



